



### **40V N-Channel Enhancement Mode MOSFET**

Voltage

40 V

Current

40 A

#### **Features**

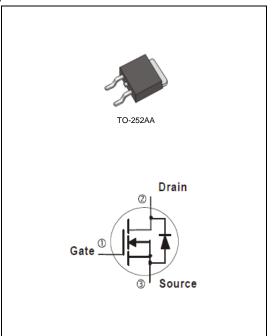
- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@20A<12m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_D@10A<17m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard



• Case: TO-252AA Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Weight: 0.0104 ounces, 0.297grams



# $\textbf{Maximum Ratings and Thermal Characteristics} \; (T_A = 25 ^{\circ} \text{C unless otherwise noted})$

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	40	\ \	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	40	A	
	T <sub>C</sub> =100°C		25		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	120	İ	
Power Dissipation	T <sub>C</sub> =25°C	Po	36	W	
	T <sub>C</sub> =100°C		14.4		
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	10	^	
	T <sub>A</sub> =70°C		8	А	
Power Dissipation	T <sub>A</sub> =25°C	Pb	2.0	107	
	T <sub>A</sub> =70°C		1.3	W	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	3.47	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





## **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			_			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250uA	40	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$		1	1.7	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =20A	-	10	12	mΩ
		V <sub>GS</sub> =4.5V,I <sub>D</sub> =10A	-	13	17	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =20V, I <sub>D</sub> =10A, V <sub>GS</sub> =4.5V <sup>(Note 2,3)</sup>	-	10	-	nC
Gate-Source Charge	$Q_gs$		-	3.5	-	
Gate-Drain Charge	$Q_{gd}$		-	3.6	-	
Input Capacitance	Ciss	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1040	-	pF
Output Capacitance	Coss		-	117	-	
Reverse Transfer Capacitance	Crss		-	84	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	9.4	-	ns
Turn-On Rise Time	t <sub>r</sub>	$\begin{array}{l} V_{DS}{=}20V, I_{D}{=}1A, \\ V_{GS}{=}10V, \ R_{G}{=}6\Omega \\ \text{(Note 2,3)} \end{array}$	-	19	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	66	-	
Turn-Off Fall Time	t <sub>f</sub>		-	67	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	_		-	-	40	А
Diode Forward Current	I <sub>S</sub>					
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A,V <sub>GS</sub> =0V	-	0.7	1	V

#### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%</a>.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$  =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





#### TYPICAL CHARACTERISTIC CURVES

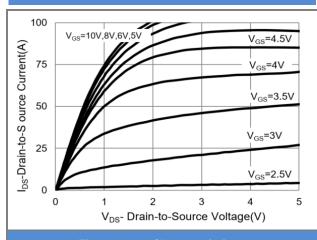
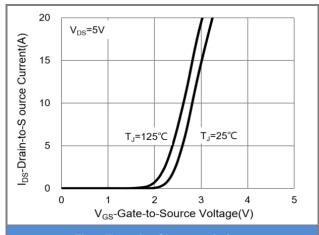


Fig.1 Output Characteristics



**Fig.2 Transfer Characteristics** 

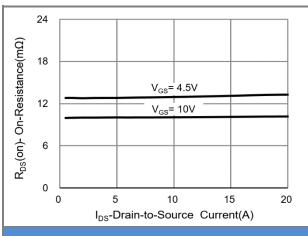


Fig.3 On-Resistance vs. Drain Current

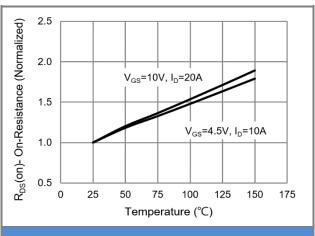


Fig.4 On-Resistance vs. Junction temperature

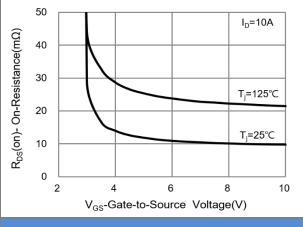


Fig.5 On-Resistance Variation with V<sub>GS</sub>

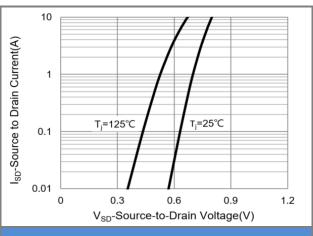


Fig.6 Source-Drain Diode Forward Voltage





#### TYPICAL CHARACTERISTIC CURVES

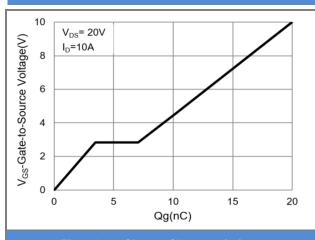


Fig.7 Gate-Charge Characteristics

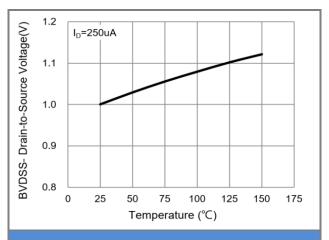


Fig.8 Breakdown Voltage Variation vs. Temperature

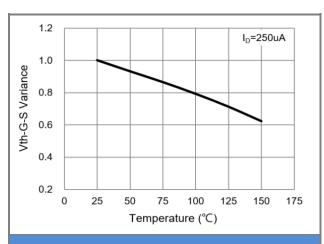


Fig.9 Threshold Voltage Variation with Temperature

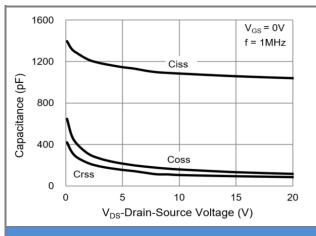
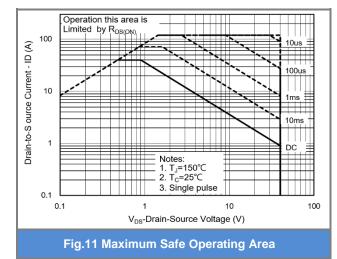
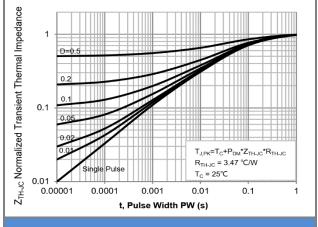


Fig.10 Capacitance vs. Drain-Source Voltage





**Fig.12 Normalized Transient Thermal Impedance** 

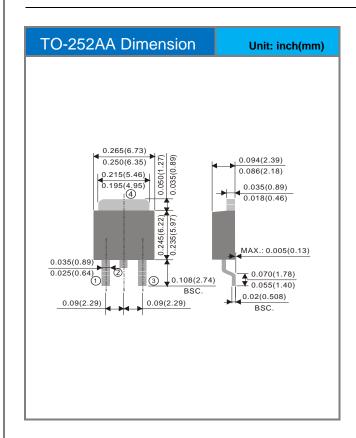


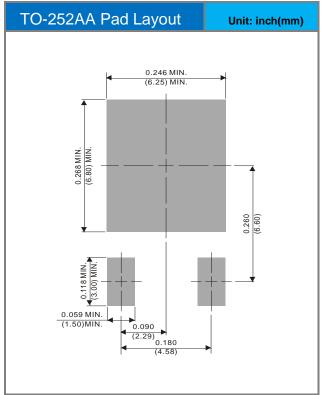


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD40N04_L2_00001	TO-252AA	3,000pcs / 13" reel	D40N04	Halogen free

### **Packaging Information & Mounting Pad Layout**









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